

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	30	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) VGs = 4V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +75°C	ID	0.5 0.4	А
Maximum Continuous Body Diode Forward Current (Note 5)			Is	0.3	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	5	A

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	350	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	357	°C/W
Total Power Dissipation (Note 6)		PD	520	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	240	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

	Symbol		_				
Characteristic		Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	-	n		n			
Drain-Source Breakdown Voltage	<b>BV</b> <sub>DSS</sub>	30	_		V	$V_{GS} = 0V, I_D = 100 \mu A$	
Zero Gate Voltage Drain Current @T <sub>C</sub> = +25°C	I <sub>DSS</sub>		_	1.0	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>		_	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.8		1.6	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance		—		1.5	Ω	$V_{GS} = 4.0V, I_{D} = 10mA$	
	R <sub>DS</sub> (ON)	—		2.0		$V_{GS} = 2.5V, I_D = 10mA$	
Diode Forward Voltage	$V_{SD}$	_		1.2	V	$V_{GS} = 0V, I_{S} = 10mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	50		pF		
Output Capacitance	Coss	—	12		pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	10		pF		
Total Gate Charge ( $V_{GS} = 4.5V$ )	Qg	_	0.5	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	1.2		nC	$V_{GS} = 10V, V_{DS} = 10V,$	
Gate-Source Charge	Qgs	—	0.2		nC	I <sub>D</sub> = 250mA	
Gate-Drain Charge	Q <sub>gd</sub>	_	0.1	_	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.5	_	ns		
Turn-On Rise Time	t <sub>R</sub>	—	3.3	—	ns	$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	16.8	—	ns	$R_{G} = 25\Omega, I_{D} = 200mA$	
Turn-Off Fall Time	t <sub>F</sub>	_	13.8	—	ns		

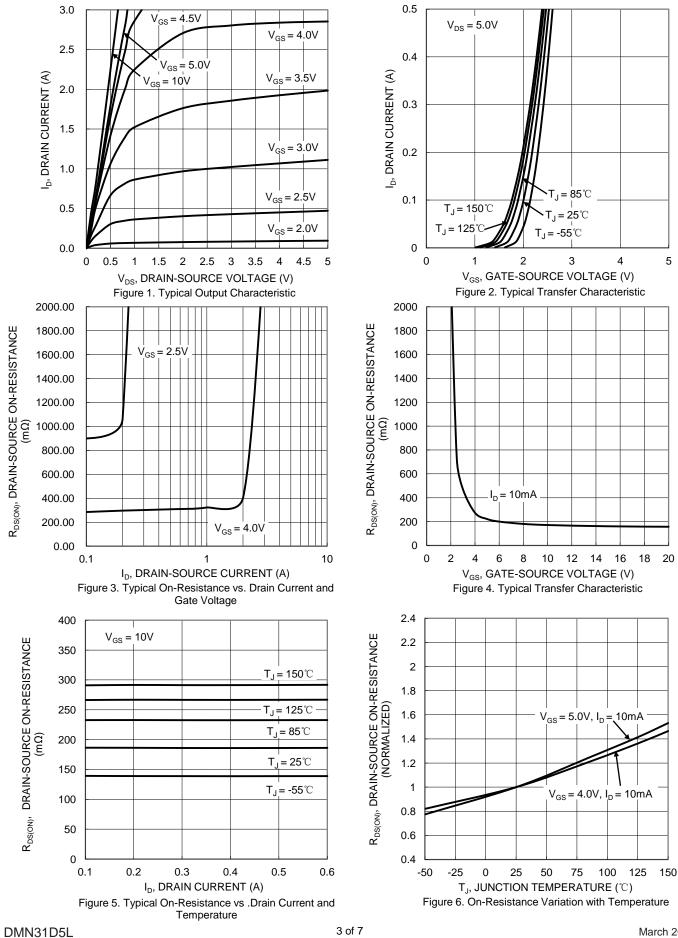
Notes:

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Device mounted on FR-4 substrate PC board, 202 copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

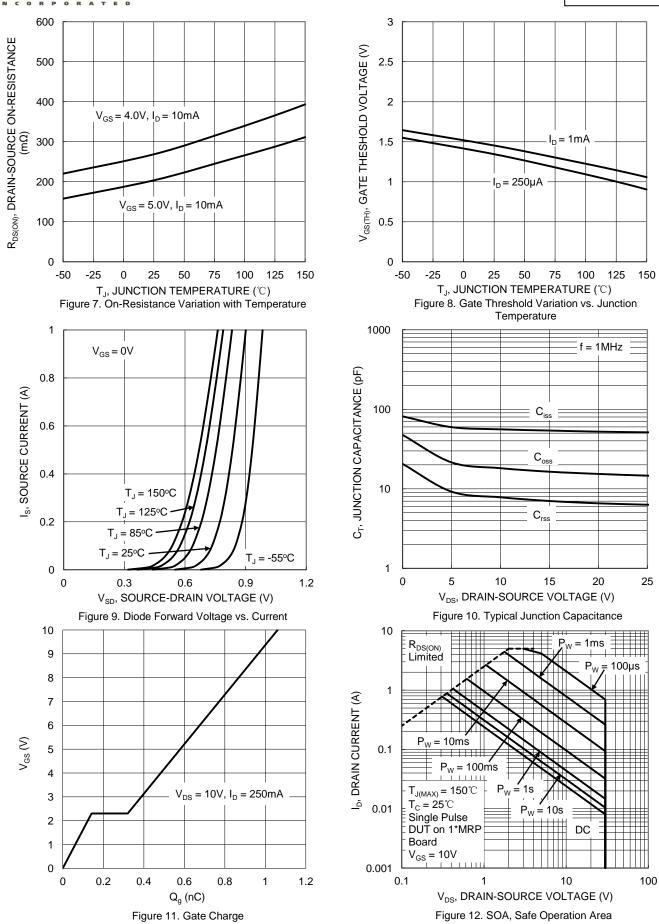




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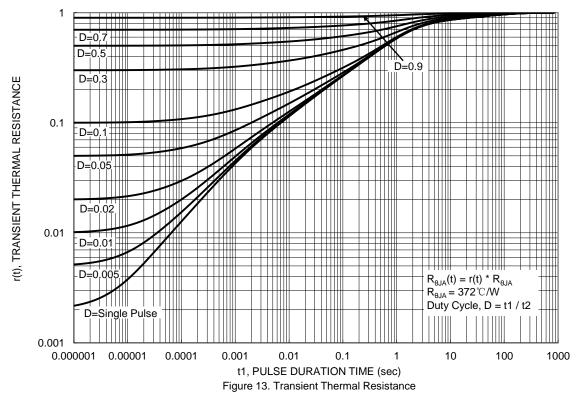






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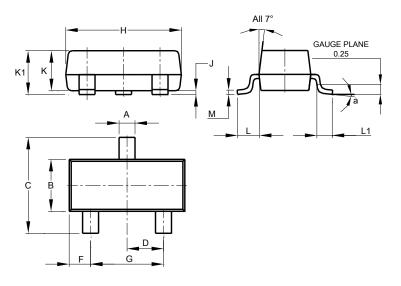


### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

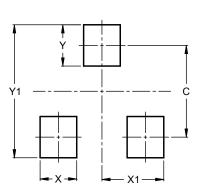
SOT23



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
ĸ	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All	All Dimensions in mm				

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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